# SWITCHMODE™ Power Rectifier

#### **Features and Benefits**

- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capacity
- 150°C Operating Junction Temperature
- 40 A Total (20 A Per Diode Leg)
- Pb-Free Packages are Available\*

# **Applications**

- Power Supply Output Rectification
- Power Management
- Instrumentation

# **Mechanical Characteristics**

- Case: Epoxy, Molded
- Epoxy Meets UL 94, V-0 @ 0.125 in
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperatures for Soldering Purposes: 260°C Max. for 10 Seconds
- ESD Rating: Human Body Model 3B

Machine Model C

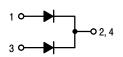
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

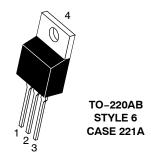


# ON Semiconductor®

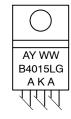
http://onsemi.com

# SCHOTTKY BARRIER RECTIFIER 40 AMPERES, 15 VOLTS





# **MARKING DIAGRAM**



A = Assembly Location

′ = Year

WW = Work Week

B4015L = Device Code

G = Pb-Free Package AKA = Polarity Designator

### **ORDERING INFORMATION**

Device	Package	Shipping
MBR4015CTL	TO-220	50 Units/Rail
MBR4015CTLG	TO-220 (Pb-Free)	50 Units/Rail

#### **MAXIMUM RATINGS**

Rating		Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	15	V
Average Rectified Forward Current (T <sub>C</sub> = 140°C per Diode) (T <sub>C</sub> = 140°C per Device)	I <sub>F(AV)</sub>	20 40	А
Peak Repetitive Forward Current, per Diode (Square Wave, 20 kHz, T <sub>C</sub> = 135°C)	I <sub>FRM</sub>	40	Α
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions, Halfwave, Single Phase, 60 Hz)	I <sub>FSM</sub>	150	Α
Peak Repetitive Reverse Surge Current (2.0 μs, 1.0 kHz)	I <sub>RRM</sub>	1.0	Α
Storage Temperature Range	T <sub>stg</sub>	-65 to +175	°C
Operating Junction Temperature (Note 1)	TJ	-65 to +150	°C
Voltage Rate of Change (Rated V <sub>R</sub> )	dv/dt	1,000	V/μs

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

# THERMAL CHARACTERISTICS (Per Diode)

Characteristic	Conditions	Symbol	Max	Unit
Maximum Thermal Resistance, Junction-to-Case	Min. Pad	$R_{\theta JC}$	1.3	°C/W
Maximum Thermal Resistance, Junction-to-Ambient	Min. Pad	$R_{\theta JA}$	70	

# **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	Min	Typical	Max	Unit
Instantaneous Forward Voltage (Note 2)	VF	1 1 1 1	0.31 0.45 0.41 0.51	0.34 0.50 0.43 0.54	V
Instantaneous Reverse Current (Note 2) (Rated dc Voltage, Tj = 125°C) (Rated dc Voltage, Tj = 25°C)	İR		300 0.8	600 10	mA

<sup>2.</sup> Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

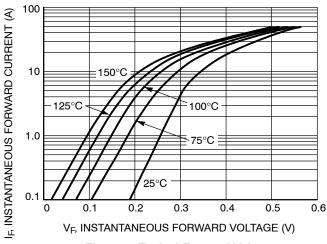


Figure 1. Typical Forward Voltage

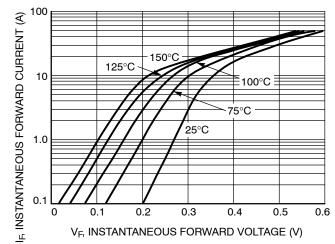
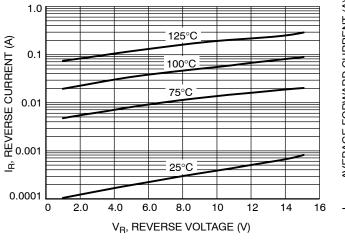


Figure 2. Maximum Forward Voltage

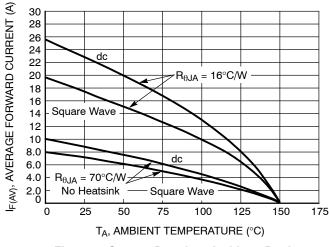
<sup>1.</sup> The heat generated must be less than the thermal conductivity from Junction–to–Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .



I<sub>F(AV)</sub>, AVERAGE FORWARD CURRENT (A) dc 28 24 Square Wave 20 16 12 8.0 4.0 0 125 130 135 140 155 145 150 T<sub>C</sub>, CASE TEMPERATURE (°C)

Figure 3. Typical Reverse Current

Figure 4. Current Derating, Case, Per Leg



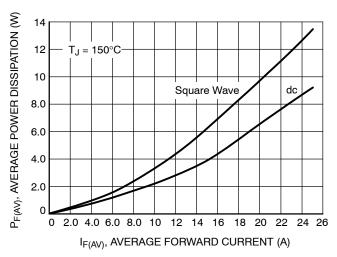


Figure 5. Current Derating, Ambient, Per Leg

Figure 6. Forward Power Dissipation

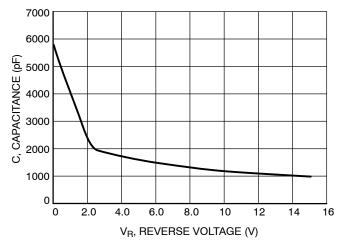
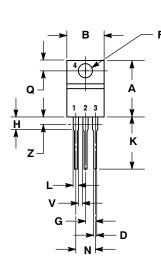
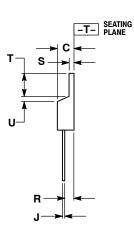


Figure 7. Typical Capacitance

### PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AF** 





#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
С	0.160	0.190	4.07	4.82	
D	0.025	0.035	0.64	0.88	
F	0.142	0.161	3.61	4.09	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.155	2.80	3.93	
J	0.014	0.025	0.36	0.64	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
Т	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
٧	0.045		1.15		
Z		0.080		2.04	

STYLE 6: PIN 1. ANODE

- 2. CATHODE
- 3 ANODE CATHODE

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